NSN 5962-01-306-5562

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Body Length:
1.490 inches
Body Width:
Between 0.500 inches and 0.610 inches
Body Height:
Between 0.172 inches and 0.217 inches
Maximum Power Dissipation Rating:
1.0 watts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
End Application:
1270-01-142-2855 target designat
Features Provided:
Hermetically sealed and burn in and programmable and erasable
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Complementary-metal oxide-semiconductor logic
Input Circuit Pattern:
26 input
Case Outline Source And Designator:
D-10 mil-m-38510
Current Rating Per Characteristic:
80.00 milliamperes total supply
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
6.25 volts total supply
Time Rating Per Chacteristic:
250.00 nanoseconds propagation delay time, low to high level output and 250.00 nanoseconds propagation delay time, high to low level
output
Memory Device Type:
Eeprom
Memory Capacity:
Unknown

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

Terminal Type And Quantity:

Test Data Document:

28 printed circuit

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•	n	0 1	•	12	e:

N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

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